

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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430V 20A Ignition IGBT

BV _{CES}	430±30V
I _C	20A
V _{CE(sat) (Typ.)}	1.6V
E _{AS}	250mJ

Features

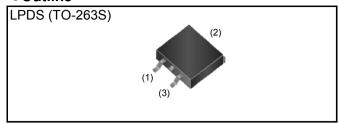
- 1) Low Collector Emitter Saturation Voltage
- 2) High Self-Clamped Inductive Switching Energy
- 3) Built in Gate-Emitter Protection Diode
- 4) Built in Gate-Emitter Resistance
- 5) Qualified to AEC-Q101
- 6) Pb free Lead Plating; RoHS Compliant

Applications

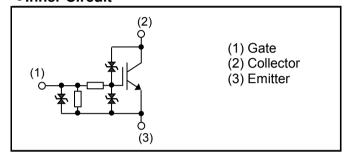
Ignition Coil Driver Circuits

Solenoid Driver Circuits

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Taping
	Reel Size (mm)	330
Typo	Tape Width (mm)	24
Туре	Basic Ordering Unit (pcs)	1,000
	Packing Code	TL
	Marking	RGPR20NS43

● **Absolute Maximum Ratings** (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	460	V
Emitter-Collector Voltage (V _{GE} = 0\	/)	V _{EC}	25	V
Gate - Emitter Voltage		V _{GES}	±10	V
Collector Current	I _C	20	А	
Avalancha Energy (Cingle Dulce)	T _j = 25°C	E _{AS}	250	mJ
Avalanche Energy (Single Pulse)	T _j = 150°C	E _{AS} *2	150	mJ
Power Dissipation		P _D	107	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature	T _{stg}	-55 to +175	°C	

●Thermal Resistance

Parameter	Symbol	Values			Unit
raiametei	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-c})}$	ı	-	1.40	°C/W

●Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Darameter	Symbol	Conditions	Values			Linit
Parameter			Min.	Тур.	Max.	Unit
		$I_C = 2mA, V_{GE} = 0V$				
Collector - Emitter Breakdown Voltage	BV _{CES}	T _j = 25°C	400	430	460	V
		$T_j = -40 \text{ to } 175^{\circ}\text{C}^{*2}$	395	-	465	V
Emitter - Collector Breakdown Voltage	BV _{EC}	$I_{C} = -10 \text{mA}, V_{GE} = 0 \text{V}$	25	35	1	٧
Gate - Emitter Breakdown Voltage	BV _{GES}	$I_G = \pm 5$ mA, $V_{CE} = 0$ V	±12	1	±17	V
		$V_{CE} = 300V, V_{GE} = 0V$				
Collector Cut - off Current	I _{CES}	T _j = 25°C	-	-	7	μΑ
		$T_j = 150^{\circ}C^{*2}$	-	-	100	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 10V, V_{CE} = 0V$	±0.4	±0.6	±1.2	mA
		$V_{CE} = 5V, I_{C} = 10mA$				
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	T _j = 25°C	1.3	1.7	2.1	V
		$T_j = 150^{\circ}C^{*2}$	-	1.3	-	V
		$I_{\rm C}$ = 10A, $V_{\rm GE}$ = 5V				
Collector - Emitter Saturation Voltage	V _{CE(sat)}	T _j = 25°C	-	1.60	2.00	V
		T _j = 150°C	-	1.80	-	V
		$I_C = 4A, V_{GE} = 4.5V$				
Collector - Emitter Saturation Voltage	V _{CE(sat)}	T _j = 25°C	-	1.17	1.50	V
		T _j = 150°C	-	1.13	-	V

●Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter Symbol Cond	Symbol	Conditions	Values			Linit
	Conditions	Min.	Тур.	Max.	Unit	
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	I_{C} = 10A, V_{GE} = 4V T_{j} = 25°C T_{j} = 150°C	-	1.70 1.90	2.10	V V
Input Capacitance	C _{ies}	V _{CE} = 10V	-	1000	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	175	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	55	-	
Total Gate Charge	Q_g	$V_{CE} = 12V, I_{C} = 10A,$ $V_{GE} = 5V$	-	14	-	nC
Turn - on Delay Time*1,*2	t _{d(on)}		0.09	0.17	0.50	
Rise Time*1,*2	t _r	$I_C = 8A, V_{CC} = 300V,$ $V_{GE} = 5V, R_G = 100\Omega,$	0.10	0.18	0.50	μs
Turn - off Delay Time*1,*2	t _{d(off)}	$L=5mH, T_j=25^{\circ}C$	0.8	1.3	4.0	
Fall Time*1,*2	t _f		1.4	2.4	6.0	
Turn - on Delay Time ^{*1}	$t_{d(on)}$		ı	0.16	ı	
Rise Time ^{*1}	t _r	$I_C = 8A, V_{CC} = 300V,$ $V_{GE} = 5V, R_G = 100\Omega,$	ı	0.23	ı	lue.
Turn - off Delay Time*1	$t_{\text{d(off)}}$	L=5mH, T _j =150°C	-	1.5	-	μs
Fall Time ^{*1}	t_f		-	3.9	-	
Avelously Francis (Circle Dules)	E _{AS}	$L = 5mH, V_{GE} = 5V,$ $V_{CC} = 30V, R_G = 1k\Omega,$				
Avalanche Energy (Single Pulse)		$T_j = 25^{\circ}C$ $T_j = 150^{\circ}C^{*2}$	250	-	-	mJ
		$T_j = 150^{\circ}C^{*2}$	150	-	-	mJ
Gate Series Resistance	R_G		70	100	130	Ω
Gate - Emitter Resistance	R_GE		8	16	24	kΩ

^{*1)} Assurance items according to our measurement definition (Fig.18)

^{*2)} Design assurance items

Electrical Characteristic Curves

Fig.1 Typical Output Characteristics

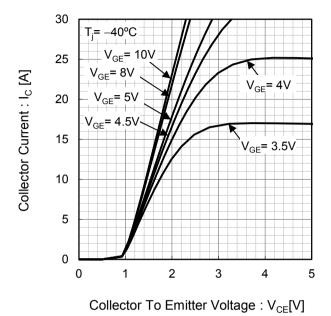
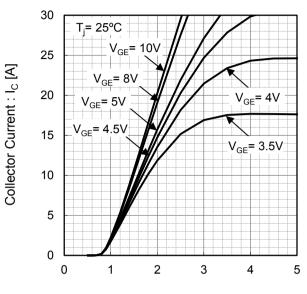


Fig.2 Typical Output Characteristics



Collector To Emitter Voltage: V_{CE}[V]

Fig.3 Typical Output Characteristics

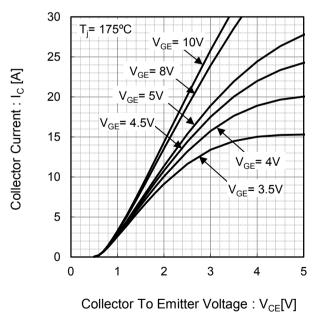
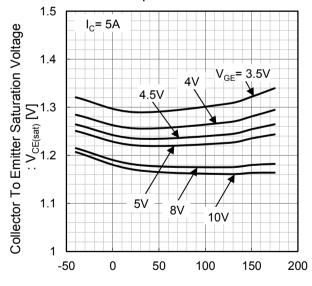


Fig.4 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

Electrical Characteristic Curves

Fig.5 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

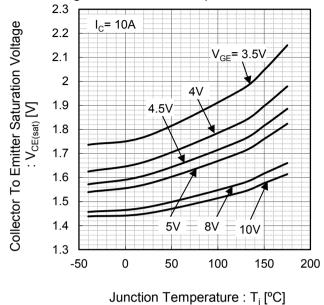
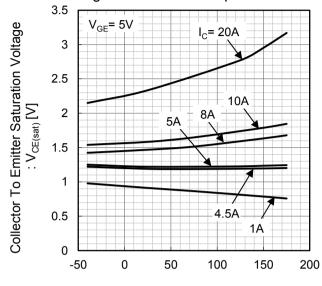


Fig.6 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

Fig.7 Typical Transfer Characteristics

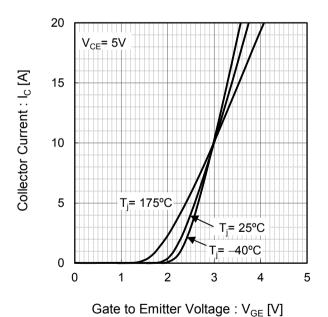
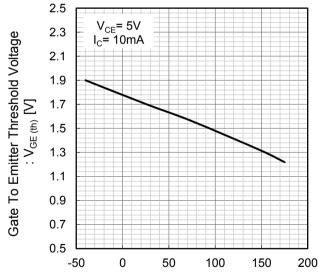
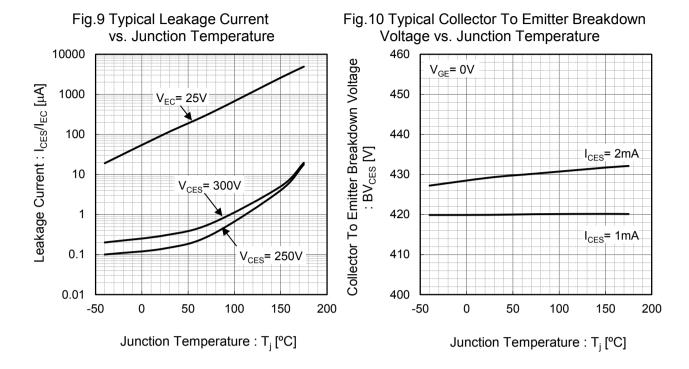


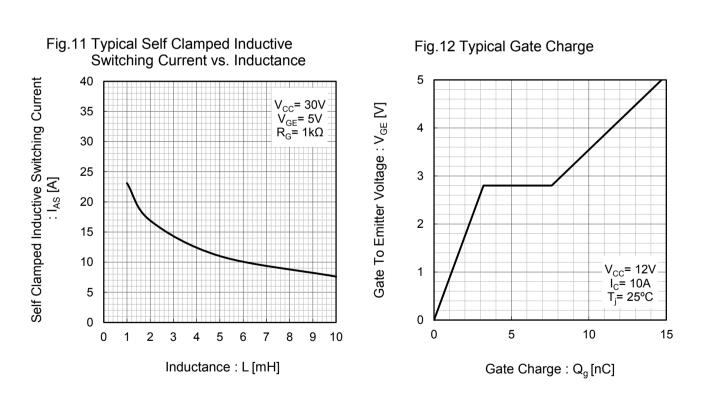
Fig.8 Typical Gate To Emitter Threshold Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

•Electrical Characteristic Curves





• Electrical Characteristic Curves

Fig.13 Typical Capacitance vs. Collector To Emitter Voltage 10000 C_{ies} 1000 Capacitance [pF] 100 C_{oes} 10 f= 1MHz V_{GE}= 0V C_{res} T_i= 25°C 0.01 0.1 1 10 100

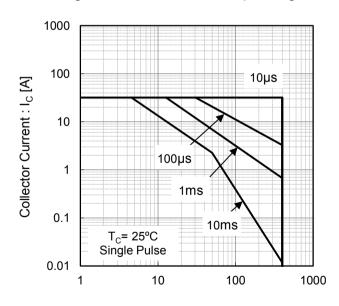
Fig. 14 Typical Switching Time vs. Junction Temperature

10 $V_{CC} = 300V, I_{C} = 8A, V_{GE} = 5V, L = 5mH$ 1
1
1
0
25 50 75 100 125 150 175 200

Junction Temperature : T_i [°C]

Fig.15 Forward Bias Safe Operating Area

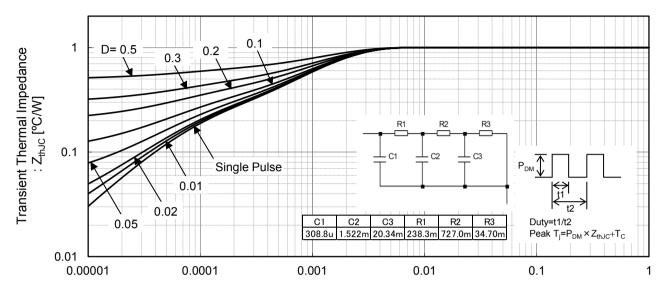
Collector To Emitter Voltage : V_{CE}[V]



Collector To Emitter Voltage : V_{CE}[V]

• Electrical Characteristic Curves

Fig.16 Transient Thermal Impedance



Pulse Width: t1[s]

●Inductive Load Switching Circuit and Waveform

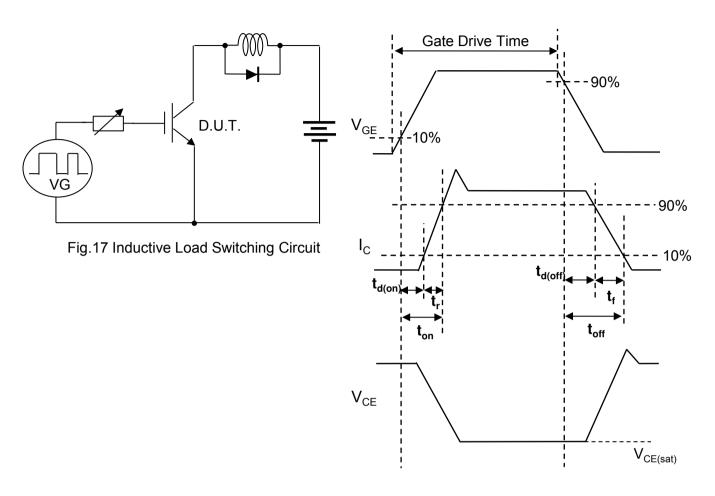


Fig.18 Inductive Load Switching Waveform

●Self Clamped Inductive Switching Circuit and Waveform

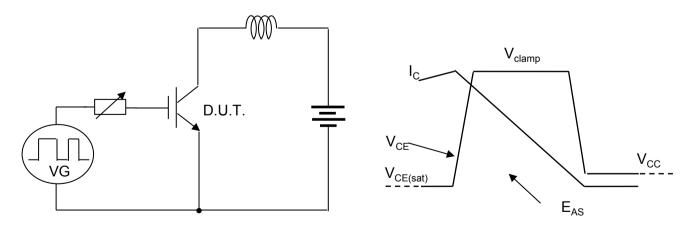


Fig.19 Self Clamped Inductive Switching Ciruit Fig.20 Self Clamped Inductive Switching Waveform

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RGPR20NS43HR - Web Page

Distribution Inventory

Part Number	RGPR20NS43HR
Package	LPDS
Unit Quantity	1000
Minimum Package Quantity	1000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes